

#### **New Product**

### **Vishay General Semiconductor**

# **Ultrafast Plastic Rectifier**

### **Major Ratings and Characteristics**

| I <sub>F(AV)</sub>  | 1.0 A        |  |  |
|---------------------|--------------|--|--|
| V <sub>RRM</sub>    | 400 V, 600 V |  |  |
| I <sub>FSM</sub>    | 35 A         |  |  |
| t <sub>rr</sub>     | 50 ns        |  |  |
| V <sub>F</sub>      | 1.05 V       |  |  |
| T <sub>j</sub> max. | 175 °C       |  |  |



#### **Features**

- · Glass passivated chip junction
- Ultrafast reverse recovery time
- · Low forward voltage drop
- · Low leakage current
- · Low switching losses, high efficiency
- · High forward surge capability
- Solder Dip 260 °C, 40 seconds

#### **Mechanical Data**

Case: DO-204AC (DO-15)

Epoxy meets UL-94V-0 Flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002B and JESD22-B102D E3 suffix for commercial grade

Polarity: Color band denotes cathode end

## **Typical Applications**

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer and Telecommunication

#### Maximum Ratings

T<sub>A</sub> = 25 °C unless otherwise specified

| Parameter  | Symbol                            | MUR140           | MUR160 | Unit |
|--|-----------------------------------|------------------|--------|------|
| Maximum repetitive peak reverse voltage  | age V <sub>RRM</sub> 400 600      |                  |        | V    |
| Working peak reverse voltage   | V <sub>RWM</sub>                  | 400              | 600    | V    |
| Maximum DC blocking voltage  | V <sub>DC</sub>                   | 400              | 600    | V    |
| Maximum average forward rectified current at $T_A = 120  ^{\circ}\text{C}$         | I <sub>F(AV)</sub>                | 1.0              |        | Α    |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | I <sub>FSM</sub>                  | 35               |        | А    |
| Operating junction and storage temperature range                                   | T <sub>J</sub> , T <sub>STG</sub> | - 65 to + 175 °C |        | °C   |

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# MUR140 & MUR160

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#### **Electrical Characteristics**

 $T_A = 25$  °C unless otherwise specified

| Parameter   | Test co  | ndition   | Symbol          | MUR140 MUR160 |   | Unit |
|---|--|---|-----------------|---------------|---|------|
| Maximum instantaneous forward voltage <sup>(1)</sup>                              | at I <sub>F</sub> = 1.0 A<br>at I <sub>F</sub> = 1.0 A                             | $T_J = 25 ^{\circ}\text{C}$<br>$T_J = 150 ^{\circ}\text{C}$ | V <sub>F</sub>  | 1.25<br>1.05  |   | V    |
| Maximum instantaneous reverse current at rated DC blocking voltage <sup>(1)</sup> |  | T <sub>J</sub> = 25 °C<br>T <sub>J</sub> = 150 °C           | I <sub>R</sub>  | 5.<br>15      |   | μА   |
| Maximum reverse recovery time   | at $I_F = 0.5 \text{ A}$ , $I_R = 1.0 \text{ A}$ , $I_{rr} = 0.25 \text{ A}$       |   | t <sub>rr</sub> | 50            |   | ns   |
| Maximum reverse recovery time   | at $I_F = 1.0$ A, di/dt = 50 A/ $\mu$ s,<br>$V_R = 30$ V, $I_{rr} = 10$ % $I_{RM}$ |   | t <sub>rr</sub> | 75            |   | ns   |
| Maximum forward recovery time   | at I <sub>F</sub> = 1.0 A, di/dt = 100 A/µs, recovery to 1.0 V                     |   | t <sub>fr</sub> | 5             | 0 | ns   |

#### Notes:

(1) Pulse test: 300  $\mu s$  pulse width, duty cycle  $\leq 2$  %

#### **Thermal Characteristics**

 $T_A = 25$  °C unless otherwise specified

| Parameter   | Symbol        | MUR140 | MUR160 | Unit |
|---|---------------|--------|--------|------|
| Typical thermal resistance junction to ambient <sup>(1)</sup> | $R_{	hetaJA}$ | 50     |        | °C/W |

#### Notes:

(1) Lead length = 3/8" on P.C. Board with 1.5" x 1.5" copper surface

## **Ratings and Characteristics Curves**

(T<sub>A</sub> = 25 °C unless otherwise noted)

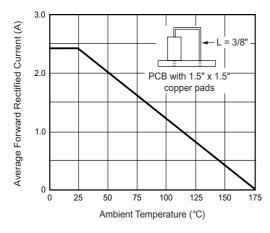


Figure 1. Forward Current Derating Curve

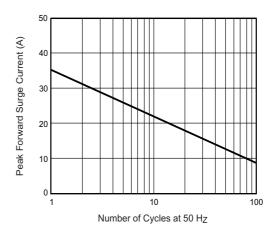


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



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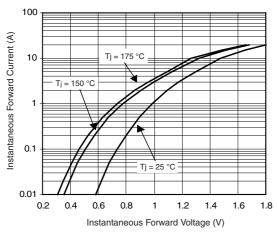


Figure 3. Typical Instantaneous Forward Characteristics

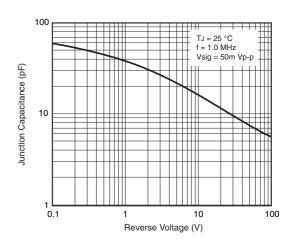


Figure 5. Typical Junction Capacitance

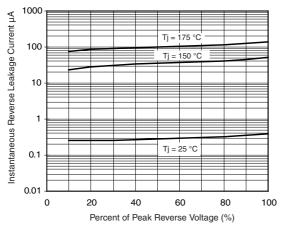
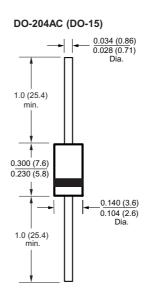


Figure 4. Typical Reverse Leakage Characteristics

# Package outline dimensions in inches (millimeters)



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